muRata

Chip Monolithic Ceramic Capacitors

Capacitor Arrays

Features

- 1. High density mounting due to mounting space saving
- 2. Mounting cost saving

Applications

General electronic equipment

GNM1M2/212				
Dant Number		Dimensio	ons (mm)	
Part Number	L	W	Т	Р
GNM1M2	1.37 ±0.15	1.0 ±0.15	0.6 ±0.1	0.64 ±0.05
GNM212	2.0 +0.15	1.25 +0.15	0.85 ±0.1	1.0 ±0.1
GNM214	2.0 ±0.15	1.25 ±0.15	0.6 ±0.1	0.5 ±0.05
GNM314	3.2 ±0.15	1.6 ±0.15	0.8 ±0.1	0.8 ±0.1
GINIVI314	J.Z ±0.15	1.0 ±0.15	1.0 ±0.1	0.0 ±0.1

Temperature Compensating Type

Part Number		GNM31		
LxW		3.2x1.6		
тс	C0G (5C)			
Rated Volt.	100 (2A)	50 (1H)		
Capacitance (Capacitance par	t numbering code) and T (mm) Dimension (Dimension part numbering code)		
10pF(100)	0.8(4)	0.8(4)		
11pF(110)	0.8(4)	0.8(4)		
12pF(120)	0.8(4)	0.8(4)		
13pF(130)	0.8(4)	0.8(4)		
15pF(150)	0.8(4)	0.8(4)		
16pF(160)	0.8(4)	0.8(4)		
18pF(180)	0.8(4)	0.8(4)		
20pF(200)	0.8(4)	0.8(4)		
22pF(220)	0.8(4)	0.8(4)		
24pF(240)	0.8(4)	0.8(4)		
27pF(270)	0.8(4)	0.8(4)		
30pF(300)	0.8(4)	0.8(4)		
33pF(330)	0.8(4)	0.8(4)		
36pF(360)	0.8(4)	0.8(4)		
39pF(390)	0.8(4)	0.8(4)		
43pF(430)	0.8(4)	0.8(4)		
47pF(470)	0.8(4)	0.8(4)		
51pF(510)	0.8(4)	0.8(4)		
56pF(560)	0.8(4)	0.8(4)		
62pF(620)	0.8(4)	0.8(4)		
68pF(680)	0.8(4)	0.8(4)		
75pF(750)	0.8(4)	0.8(4)		
82pF(820)	0.8(4)	0.8(4)		
91pF(910)	0.8(4)	0.8(4)		
100pF(101)	0.8(4)	0.8(4)		
110pF(111)	0.8(4)	0.8(4)		
120pF(121)	0.8(4)	0.8(4)		
130pF(131)	0.8(4)	0.8(4)		
150pF(151)	0.8(4)	0.8(4)		
160pF(161)		0.8(4)		
180pF(181)		0.8(4)		



Note Please read rating and
 CAUTION (for storage, operating, rating, soldering, mounting and handling) in this PDF catalog to prevent smoking and/or burning, etc.
 This catalog has only typical specifications. Therefore, you are requested to approve our product specifications or to transact the approval sheet for product specifications before ordering.

C02E10.pdf 04.1.20

Continued from the preceding page.

Part Number	GN	M31			
L x W	3.22	x1.6			
тс	C0G (5C)				
Rated Volt.	100 (2A)	50 (1H)			
Capacitance (Ca	pacitance part numbering code) and T (mm) Dimension (T Dimen	sion part numbering code)			
200pF(201)		0.8(4)			
220pF(221)		0.8(4)			
240pF(241)		0.8(4)			
270pF(271)		0.8(4)			
300pF(301)		0.8(4)			
330pF(331)		0.8(4)			
360pF(361)		0.8(4)			

The part numbering code is shown in each (). The (4) code in T(mm) means number of elements (four). Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type GNM1 Series

Part Number	GNM1M					
L x W	1.372	x1.00				
тс	X7R (R7)					
Rated Volt.	16 (1C)	10 (1A)				
Capacitance (Ca	pacitance part numbering code) and T (mm) Dimension (T Dimen	sion part numbering code)				
22000pF(223)	0.6(2)					
47000pF(473)	0.6(2)					
0.10μF(104)		0.6(2)				

The part numbering code is shown in each (). The (2) code in T(mm) means number of elements (two).

Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type GNM2 Series

Part Number	GNM21
L x W	2.0x1.25
тс	X7R (R7)
Rated Volt.	50 (1H)
Capacitance (Ca	pacitance part numbering code) and T (mm) Dimension (T Dimension part numbering code)
1000pF(102)	0.6(4)
10000pF(103)	0.6(4)

The part numbering code is shown in each (). The (4) code in T(mm) means number of elements (four). Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type GNM3 Series

Part Number	GNM31							
L x W	3.2x1.6							
тс			7R 1 7)		Y5V (F5)			
Rated Volt.	100 (2A)	50 (1H)	25 16 (1E) (1C)		100 (2A)	50 (1H)	16 (1C)	
Capacitance (Ca	pacitance part nun	nbering code) and	T (mm) Dimension	(T Dimension part	numbering code)			
220pF(221)	0.8(4)							



ANote Please read rating and ACAUTION (for storage, operating, rating, soldering, mounting and handling) in this PDF catalog to prevent smoking and/or burning, etc. This catalog has only typical specifications. Therefore, you are requested to approve our product specifications or to transact the approval sheet for product specifications before ordering.

 \square Continued from the preceding page.

Part Number				GNM31					
L×W	3.2x1.6								
тс	X7R (R7)				Y5V (F5)				
Rated Volt.	100 (2A)	50 (1H)	25 (1E)	16 (1C)	100 (2A)	50 (1H)	16 (1C)		
Capacitance (Capa	citance part nur	mbering code) and	T (mm) Dimension	(T Dimension part	numbering code)				
270pF(271)	0.8 (4)								
330pF(331)	0.8 (4)								
390pF(391)	0.8(4)	0.8(4)							
470pF(471)	0.8(4)	0.8(4)							
560pF(561)	0.8(4)	0.8(4)							
680pF(681)	0.8(4)	0.8(4)							
820pF(821)	0.8(4)	0.8(4)							
1000pF(102)	0.8(4)	0.8(4)							
1200pF(122)	0.8(4)	0.8(4)							
1500pF(152)	0.8 (4)	0.8(4)							
1800pF(182)	0.8(4)	0.8(4)							
2200pF(222)	0.8(4)	0.8(4)			0.8(4)				
2700pF(272)	0.8(4)	0.8(4)							
3300pF(332)	0.8(4)	0.8(4)			0.8(4)				
3900pF(392)	0.8 (4)	0.8(4)							
4700pF(472)	0.8 (4)	0.8(4)			0.8(4)				
5600pF(562)		0.8(4)							
6800pF(682)		0.8(4)							
8200pF(822)		0.8(4)							
10000pF(103)		0.8(4)							
12000pF(123)		0.8(4)							
15000pF(153)		0.8(4)							
18000pF(183)			0.8(4)						
22000pF(223)				0.8(4)		0.8(4)			
27000pF(273)				0.8 (4)					
33000pF(333)				0.8(4)		0.8(4)			
39000pF(393)				0.8(4)					
47000pF(473)				1.0(4)		0.8(4)			
68000pF(683)				1.0(4)			0.8(4)		
0.10μF(104)				1.0(4)			0.8(4)		
0.15µF(154)							0.8(4)		

The part numbering code is shown in each (). The (4) code in T(mm) means number of elements (four). Dimensions are shown in mm and Rated Voltage in Vdc.



8

Specifications and Test Methods

				Specifications				
No.	lte	em	Temperature Compensating Type	High Dielectric Type		Test Method		
1	Operating Temperati		5C : −55℃ to +125℃	R7 : −55℃ to +125℃ F5 : −30℃ to +85℃				
2	Rated Vo	ltage	See the previous pages.		The rated voltage is do may be applied contin When AC voltage is so whichever is larger, sh age range.	uously to the capac uperimposed on DC	citor. C voltage,	V ^{p.p} or V ^{o.p} ,
3	Appearar	nce	No defects or abnormaliti	es	Visual inspection			
4	Dimensio	on	Within the specified dime	nsions	Using calipers			
5	Dielectric	: Strength	No defects or abnormaliti	ies	No failure should be o (5C) or 250% of the ra the terminations for 1 charge current is less	ated voltage (R7, F5 to 5 seconds, provi	5) is applie	ed between
6	Insulation	Resistance	More than 10,000M Ω or (Whichever is smaller)	500Ω • F	The insulation resistar age not exceeding the and within 2 minutes of	e rated voltage at 25		
7	Capacita	nce	Within the specified tolera 30pF min. : Q≧1000	ance	The capacitance/Q/D. quency and voltage sh		ured at 25	℃ at the fre-
	O/Discing	tion Factor	30pF max. : Q≧400+20C	Char. 25V min. 16V 10V	Item Char.		R	', F5
8	(D.F.)	lion Factor		R7 0.025 max. 0.035 max. 0.035 max.	Frequency	1±0.1MHz	1±0	.1kHz
			C : Nominal Capacitance (pF)	F5 0.05 max. 0.07 max	Voltage	0.5 to 5Vr.m.s.	1.0±0.	2Vr.m.s.
		Capacitance Change Temperature Coefficient	Within the specified tolerance (Table A) Within the specified tolerance (Table A)	Char. Temp. Range Reference Temp. Cap. Change R7 -55 to +125°C F5 -30 to +85°C 25°C Within±15% Within±232%	capacitance measu When cycling the te through 5, the capa	ature stage. pensating Type pefficient is determi ured in step 3 as a r emperature sequen acitance should be v	ned using reference. tially from within the	the step1 specified
9	Capacitance Temperature				tolerance for the te change as Table A The capacitance dr differences betwee values in steps 1, 3	ift is calculated by c n the maximum and	lividing the	e n measured
	Characteristics				Step	Tempera		
		Canaaltanaa	Within ±0.2% or ±0.05 pF		2	25		(for 55)
		Capacitance	(Whichever is larger)		3	-55±3 (for 5C/ R7 25±		(101 F5)
					4	125±3 (for 5C/F		(E5)
					5	255		()
						acitance change con	e ranges s	
		1	No removal of the termination	ations or other defect should occur.	Solder the capacitor to	o the test jig (glass o	epoxy boa	ard) shown in
10	Adhesive	Strength			Fig. 1 using a eutectic with the test jig for 10- The soldering should I reflow method and sho soldering is uniform ar	solder. Then apply ±1 sec. be done either with ould be conducted v	5N force an iron or with care	in parallel using the so that the
10	of Termir				Туре	a b	с	d
					GNM1M GNM21	0.5 – 0.4 1.6	0.32	0.32
					GNM21 GNM31	0.4 1.6	0.25	0.8
				Solder resist		Fig. 1		(in mm)
						, ,		

Continued on the following page.



Specifications and Test Methods

Continued from the preceding page.

<u> </u>	Continued fr			Specifications	
lo.	. Item		Temperature		Test Method
			Compensating Type	High Dielectric Type	
		Appearance	No defects or abnormaliti	ies	Solder the capacitor to the test jig (glass epoxy board) in the
		Capacitance	Within the specified tolera	ance	same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmonic motior
11	Vibration Resistance	Q/D.F.	30pF min. : Q≥1000 30pF max. : Q≥400+20C C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should be traversed in approximately 1 minute. This motion should be applied for a period of 2 hours in each of 3 mutually perpendicular directions (total of 6 hours).
			No cracking or marking d	lefects should occur.	Solder the capacitor on the test jig (glass epoxy board) shown
12	2 Deflection		ion $GNM \square 4$ •GNM \square 2		in Fig. 2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3 for 5±1 sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. $\begin{array}{c} 20 \\ 100 $
				(in mm) Fig. 2	t=0.8mm (GNM21), 1.6mm (GNM31)
13	Solderabi Terminati	2	75% of the terminations a continuously.	are to be soldered evenly and	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120°C for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2±0.5 seconds at 230±5°C.
			The measured and obser specifications in the follow	rved characteristics should satisfy the wing table.	
		Appearance	No marking defects		Preheat the capacitor at 120 to 150°C for 1 minute. Immerse the
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	R7 : Within ±7.5% F5 : Within ±20%	capacitor in a eutectic solder solution at $270\pm5^{\circ}$ for 10 ± 0.5 seconds. Let sit at room temperature for 24 ± 2 hours (tempera- ture compared in a trac) of 42 ± 4 hours (high dislocating compared
4	Resistance to Soldering Heat	Q/D.F.	30pF min. : Q≥1000 30pF max. : Q≥400+20C C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	 ture compensating type) or 48±4 hours (high dielectric constant type), then measure. Initial measurement for high dielectric constant type Perform a heat treatment at 150±40 °C for one hour and then let sit for 48±4 hours at room temperature. Perform the initial
		I.R.	More than 10,000M Ω or \pm	500 Ω • F (Whichever is smaller)	measurement.
		Dielectric Strength	No failure		
			The measured and obser specifications in the follow	rved characteristics should satisfy the wing table.	Fix the capacitor to the supporting jig in the same manner and under the same conditions as (10). Perform the five cycles
		Appearance	No marking defects		according to the four heat treatments listed in the following
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	R7 : Within ±7.5% F5 : Within ±20%	 table. Let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room tempera- ture, then measure
5	Temperature Cycle	Q/D.F.	30pF min. : Q≧1000 30pF max. : Q≧400+20C C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	Step 1 2 3 4 Temp. (°C) Min. Operating Temp. ±3 Room Temp. ±3 Max. Operating Temp. ±3 Room Temp. ±3 Time (min.) 30±3 2 to 3 30±3 2 to 3
		I.R.		500Ω • F (Whichever is smaller)	• Initial measurement for high dielectric constant type Perform a best treatment at 150^{+9} , ∞ for one bour and then
		Dielectric		(Perform a heat treatment at $150 \stackrel{+}{\to} _{0}^{\circ} ^{\circ} C$ for one hour and then let sit for 48 ± 4 hours at room temperature. Perform the initial

Continued on the following page.



8

Specifications and Test Methods

Continued from the preceding page.

L	Continued fr	om the prec	eding page.			
				Specifications		
No.	b. Item		Temperature Compensating Type	High Dielectric Type	Test Method	
			The measured and observed characteristics should satisfy the specifications in the following table.			
		Appearance	No marking defects			
		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	R7 : Within ±12.5% F5 : Within ±30%	Let the capacitor sit at 40±2℃ and 90 to 95% humidity for	
16	Humidity Steady State	Q/D.F.	30pF and over : Q≧350 10pF and over, 30pF and below : Q≧275+5C/2 10pF and below : Q≧200+10C C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure.	
		I.R.	More than 1,000M Ω or 50	0Ω • F (Whichever is smaller)		
		Dielectric Strength	No failure			
			The measured and obser specifications in the follow	ved characteristics should satisfy the wing table.		
		Appearance	No marking defects			
		Capacitance Change	Within ±7.5% or ±0.75pF (Whichever is larger)	R7 : Within ±12.5% F5 : Within ±30%		
17	Humidity Load	Q/D.F.	30pF and over : Q≥200 30pF and below : Q≥100+10C/3 C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. - -	Apply the rated voltage at 40±2°C and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA.	
		I.R.	More than 500M Ω or 25 Ω	2 • F (Whichever is smaller)		
		Dielectric Strength	No failure			
		The measured and observed characteristics should satisfy the specifications in the following table.		-		
		Appearance	No marking defects			
		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	R7 : Within ±12.5% F5 : Within ±30%	Apply 200% of the rated voltage for 1000 ± 12 hours at the	
18	High Temperature Load	Q/D.F.	30pF and over : $Q \ge 350$ 10pF and over, 30pF and below : $Q \ge 275+5C/2$ 10pF and below : $Q \ge 200+10C$ C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	 maximum operating temperature ±3°C. Let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA. Initial measurement for high dielectric constant type. Apply 200% of the rated DC voltage for one hour at the maximum operating temperature ±3°C. Remove and let sit for 48±4 hours at room temperature. Perform initial measurement. 	
		I.R.		ΩΩ • F (Whichever is smaller)	-	
		Dielectric Strength	No failure			

Table A

Char. Nominal Values -55 -30		
(npm/°) Note 1	-10	
(ppm/°C) Note 1 Max. Min. Max. Min. Max.	Min.	
5C 0±30 0.58 -0.24 0.40 -0.17 0.25	-0.11	

Note 1 : Nominal values denote the temperature coefficient within a range of 25°C to 125°C.

